

6427525 N E C ELECTRONICS INC

81C 10093 D T-79-15

**NEC**

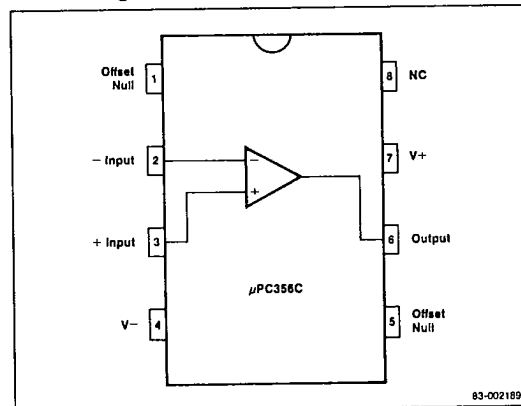
NEC Electronics Inc.

 **$\mu$ PC356  
J-FET INPUT  
OPERATIONAL AMPLIFIER****Description**

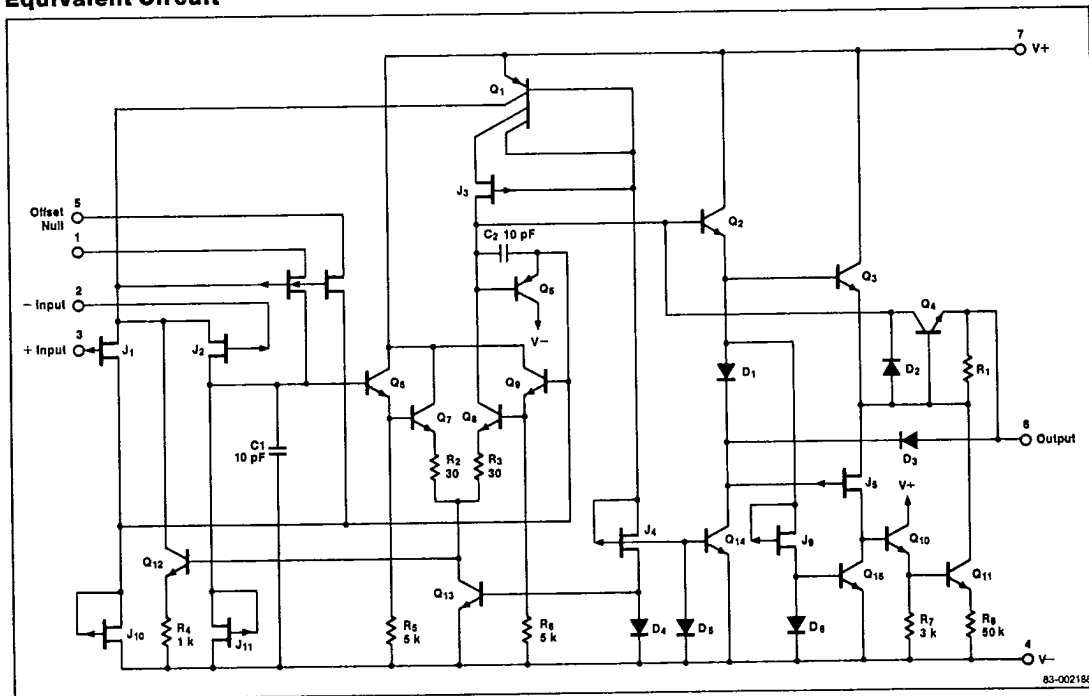
The  $\mu$ PC356 is a J-FET input operational amplifier with matched P-channel ion implanted J-FETs. In addition to the obvious advantages of J-FET inputs, the  $\mu$ PC356 is designed for high slew rate, wide bandwidth, and extremely fast settling time.

**Features**

- ☐ Low input offset voltage: 5 mV max (trimming technique used)
- ☐ Offset adjust does not degrade drift or CMRR
- ☐ The NPN sink output stage allows use of large capacitive loads (10,000 pF) without a stability problem
- ☐ Internal compensation and large differential input voltage capability
- ☐ LF356 equivalent

**Pin Configuration**

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**Equivalent Circuit**

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**NEC****μPC356****Ordering Information**

| Part Number | Package     | Operating Temperature Range |
|-------------|-------------|-----------------------------|
| μPC356C     | Plastic DIP | 0°C to +70°C                |

**Electrical Characteristics** $T_A = 25^\circ\text{C}$ ,  $V_{\pm} = \pm 15\text{ V}$ 

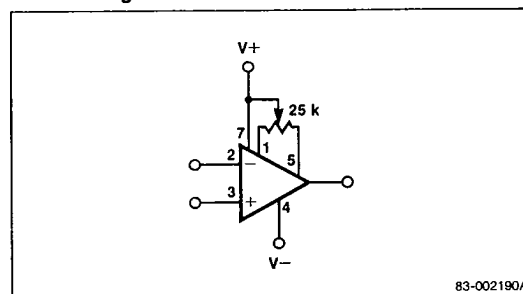
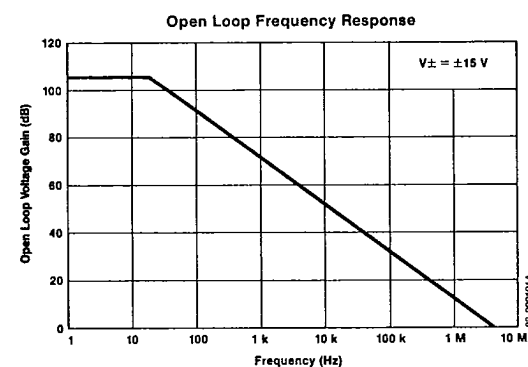
| Parameter                               | Symbol                   | Limits   |                     |      | Unit                         | Test Conditions                                          |
|-----------------------------------------|--------------------------|----------|---------------------|------|------------------------------|----------------------------------------------------------|
|                                         |                          | Min.     | Typ.                | Max. |                              |                                                          |
| Input Offset Voltage                    | $V_{IO}$                 | 2        | 5                   |      | mV                           | $R_S \leq 50\ \Omega$                                    |
| Input Offset Current                    | $I_{IO}$                 | 3        | 50                  |      | pA                           |                                                          |
| Input Bias Current                      | $I_b$                    | 30       | 200                 |      | pA                           |                                                          |
| Large Signal Voltage Gain               | $A_{VOL}$                | 88       | 106                 |      | dB                           | $R_L \geq 2\text{ k}\Omega$ ,<br>$V_O = \pm 10\text{ V}$ |
| Supply Current                          | $I_{CC}$                 | 5        | 10                  |      | mA                           |                                                          |
| Common Mode Rejection Ratio             | CMRR                     | 80       | 100                 |      | dB                           |                                                          |
| Supply Voltage Rejection Ratio          | SVRR                     | 80       | 100                 |      | dB                           |                                                          |
| Output Voltage Swing                    | $V_{OM}$                 | $\pm 12$ | $\pm 13$            |      | V                            | $R_L \geq 10\text{ k}\Omega$                             |
|                                         |                          | $\pm 10$ | $\pm 12$            |      | V                            | $R_L \geq 2\text{ k}\Omega$                              |
| Common Mode Voltage                     | $V_{ICM}$                | $\pm 10$ | $\pm 15.1$<br>$-12$ |      | V                            |                                                          |
| Slew Rate                               | SR                       | 12<br>20 |                     |      | V/ $\mu\text{s}$             | Rise                                                     |
|                                         |                          |          |                     |      | V/ $\mu\text{s}$             | Fall                                                     |
| Input Noise Voltage                     | $e_n$                    | 20       |                     |      | nV/ $\sqrt{\text{Hz}}$       | $f = 1\text{ kHz}$ ,<br>$R_1 = 100\ \Omega$              |
| Gain Bandwidth Products                 | GBW                      | 5        |                     |      | MHz                          |                                                          |
| <b>Over Operating Temperature Range</b> |                          |          |                     |      |                              |                                                          |
| Input Offset Voltage                    | $V_{IO}$                 |          | 7                   |      | mV                           | $R_S \leq 50\ \Omega$ ,<br>$T_A = T_{OPT}$               |
| Offset Voltage Drift                    | $\Delta V_{IO}/\Delta T$ |          | 5                   |      | $\mu\text{V}/^\circ\text{C}$ | $T_A = T_{OPT}$                                          |
| Input Bias Current                      | $I_b$                    |          | 8                   |      | nA                           | $T_A = T_{OPT}$                                          |
| Input Offset Current                    | $I_{IO}$                 |          | 2                   |      | nA                           | $T_A = T_{OPT}$                                          |

**Absolute Maximum Ratings** $T_A = 25^\circ\text{C}$ 

|                                 |                   |
|---------------------------------|-------------------|
| Voltage Between $V^+$ and $V^-$ | 36 V              |
| Power Dissipation               | 350 mW            |
| Differential Input Voltage      | $\pm 30\text{ V}$ |
| Input Voltage (Note 1)          | $\pm 15\text{ V}$ |
| Output Short Circuit Duration   | Indefinite        |
| Operating Temperature Range     | 0 to +70°C        |
| Storage Temperature Range       | -55 to +125°C     |

Note 1. For supply voltages less than  $\pm 15\text{ V}$ , the absolute maximum input voltage is equal to the supply voltage.

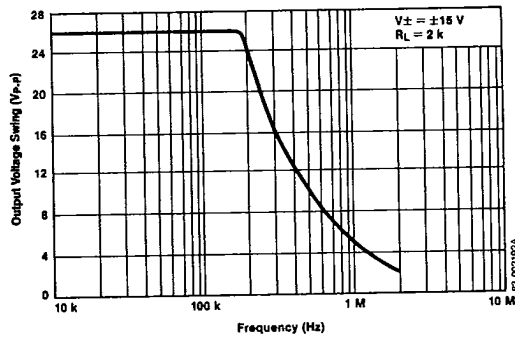
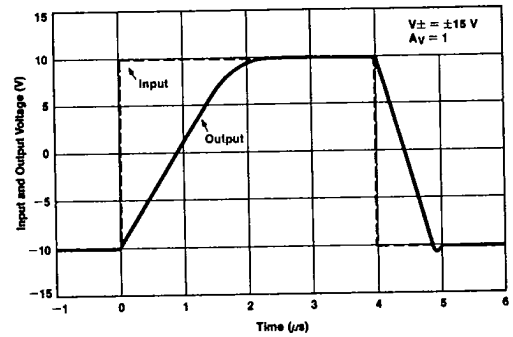
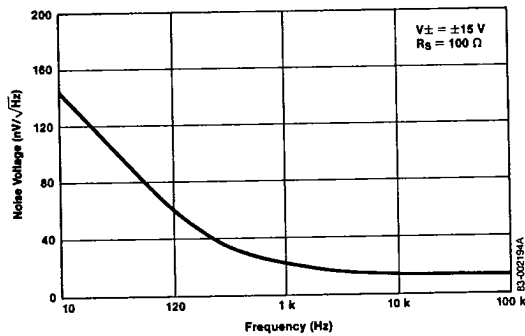
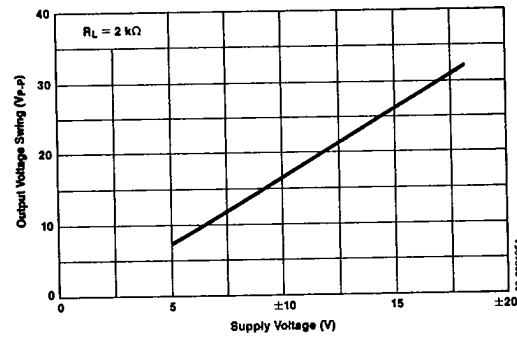
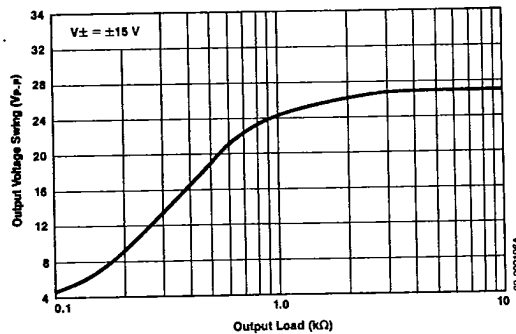
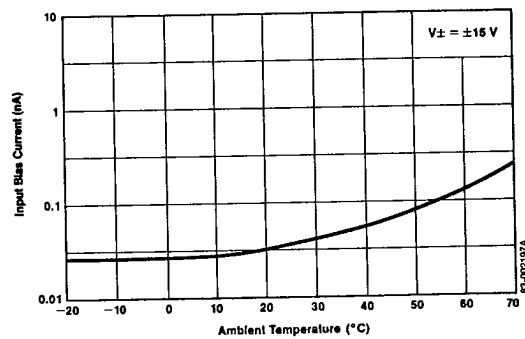
Comment: Stress above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Typical Application****Offset Voltage Null Circuit****Operating Characteristics** $T_A = 25^\circ\text{C}$ 

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**NEC** **$\mu$ PC356****Operating Characteristics (Cont.)** $T_A = 25^\circ\text{C}$ **Undistorted Output Voltage Swing****Voltage Follower Pulse Response****Input Equivalent Noise****Voltage Swing****Voltage Swing****Input Bias Current****3**

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